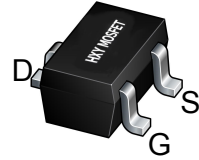




Description

The HXY2101EI uses advanced trench technology to provide excellent $R_{DS(ON)}$. This device is suitable for use as a load switch or in PWM applications.



SOT-323

General Features

$V_{DS} = -20V, I_D = -1.8A$

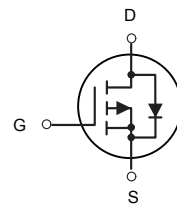
$R_{DS(ON)} < 150m\Omega @ V_{GS} = -4.5V$

Application

Battery protection

Load switch

Uninterruptible power supply



P-Channel MOSFET

Package Marking and Ordering Information

| Product ID | Pack | Marking | Qty(PCS) |
|------------|---------|---------|----------|
| HXY2101EI | SOT-323 | TS1 | 3000 |

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Limit | Unit |
|-----------------|--|------------|------|
| V_{DS} | Drain-Source Voltage | -20 | V |
| V_{GS} | Gate-Source Voltage | ± 8 | V |
| I_D | Drain Current-Continuous | -1.8 | A |
| I_{DM} | Drain Current-Pulsed (Note 1) | -3 | A |
| P_D | Maximum Power Dissipation | 0.29 | W |
| T_J, T_{STG} | Operating Junction and Storage Temperature Range | -55 To 150 | °C |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient (Note 2) | 431 | °C/W |



Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

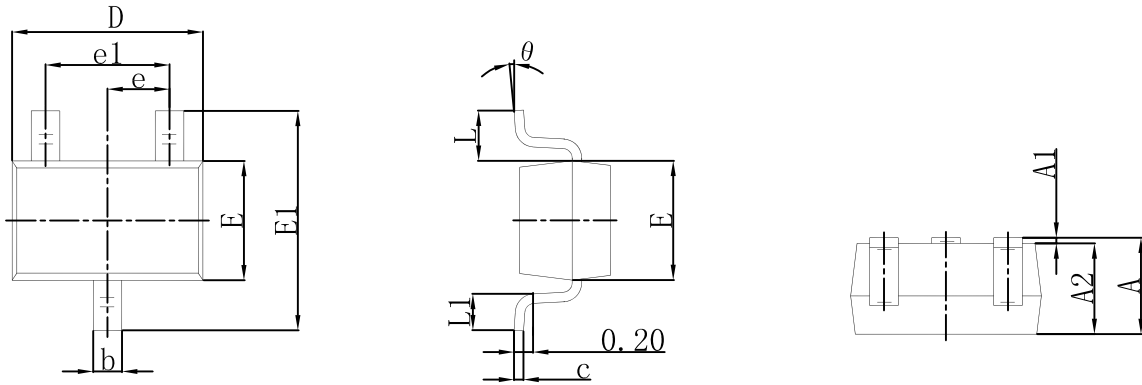
| Parameter | Symbol | Test conditions | Min | Typ | Max | Unit |
|--|---------------|--|------|------|-----------|------------|
| STATIC CHARACTERISTIC | | | | | | |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = -250\mu A$ | -20 | | | V |
| Zero gate voltage drain current | I_{DSS} | $V_{DS} = -18V, V_{GS} = 0V$ | | | -1 | μA |
| Gate-body leakage current | I_{GSS} | $V_{GS} = \pm 12V, V_{DS} = 0V$ | | | ± 100 | nA |
| Gate threshold voltage <small>(note2)</small> | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = -250\mu A$ | -0.4 | -0.7 | -1.0 | V |
| Drain-source on-resistance <small>(note2)</small> | $R_{DS(on)}$ | $V_{GS} = -4.5V, I_D = -2A$ | | | 150 | m Ω |
| | | $V_{GS} = -2.5V, I_D = -1.0A$ | | | 230 | m Ω |
| Maximum Continuous Drain to Source Diode Forward Current | I_S | -- | | | -1.0 | A |
| Diode forward voltage | V_{SD} | $I_S = -1.0A, V_{GS} = 0V$ | | | -1.2 | V |
| DYNAMIC CHARACTERISTICS <small>(note3)</small> | | | | | | |
| Input capacitance | C_{iss} | $V_{DS} = -8V, V_{GS} = 0V,$ $f = 1MHz$ | | | 680 | pF |
| Output capacitance | C_{oss} | | | | 130 | pF |
| Reverse transfer capacitance | C_{rss} | | | | 95 | pF |
| SWITCHING CHARACTERISTICS <small>(note3)</small> | | | | | | |
| Turn-on delay time | $t_{d(on)}$ | $V_{GS} = -4.5V, V_{DS} = -10V,$ $I_D = -1.0A, R_G = 5.1\Omega$ | | | 10 | nS |
| Turn-on rise time | t_r | | | | 20 | nS |
| Turn-off delay time | $t_{d(off)}$ | | | | 35 | nS |
| Turn-off fall time | t_f | | | | 18 | nS |

Notes:

1. Surface mounted on FR4 board using the minimum recommended pad size.
2. Pulse Test : Pulse Width=300 μs , Duty Cycle=2%.
3. These parameters have no way to verify.



SOT-323 Package Outline Dimensions



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 0.900 | 1.100 | 0.035 | 0.043 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 0.900 | 1.000 | 0.035 | 0.039 |
| b | 0.200 | 0.400 | 0.008 | 0.016 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 2.000 | 2.200 | 0.079 | 0.087 |
| E | 1.150 | 1.350 | 0.045 | 0.053 |
| E1 | 2.150 | 2.450 | 0.085 | 0.096 |
| e | 0.650 TYP | | 0.026 TYP | |
| e1 | 1.200 | 1.400 | 0.047 | 0.055 |
| L | 0.525 REF | | 0.021 REF | |
| L1 | 0.260 | 0.460 | 0.010 | 0.018 |
| θ | 0° | 8° | 0° | 8° |



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